

AMENDMENTS TO THE SPECIFICATION

- 1. Please replace the paragraph bridging pages 1 and 2, at lines 24-26 on page 1, and lines 1-7 on page 2, of the specification with the following amended paragraph:**

When an electric field is applied to an organic EL device of a stacked body of an organic light emitting layer and an electron or hole transport layer, holes are injected from the anode and electrons are injected from the cathode. The organic EL ~~device~~device utilizes emission of light that is emitted when the electrons and the holes are recombined in the organic light emitting layer to form exciters and they are returned to the ground state. For making the luminous efficiency higher and stably driving the device, a dye is sometimes doped as a guest material to the light emitting layer.

- 2. Please replace the paragraph on page 3 at lines 3-18 of the specification with the following amended paragraph:**

In existent organic EL devices utilizing phosphorescence emission, hole transporting materials capable of transporting holes have been used for the light emitting layer host material and materials having higher ionizing potential energy (Ip) than the host material of the light emitting layer such as phenanthroline derivatives, for example, 2,9-dimethyl-4,7-diphenyl-1,10-phenanthroline, i.e., BCP or aluminum chelate complex, for example, ((1,1'-biphenyl)-4-olato)bis(2-methyl-8-quinolinolato) Al, i.e., BAQ are used as the hole blocking layer in the layer adjacent to the cathode side of the light emitting layer. In a case of using BCP for the hole blocking layer, while the emission characteristics at the initial stage are favorable, it involves a drawback that the driving life is extremely short. At present, materials having sufficiently high Ip and excellent in durability have not been known.

3. Please replace the paragraph on page 4 at lines 9-10 of the specification with the following amended paragraph:

It is an object of the present invention to provide an organic EL device capable of prolonging the ~~life~~lifetime of the device.

4. Please replace the paragraph on page 5 at lines 1-3 of the specification with the following amended paragraph:

The electroluminescence device according to the invention is characterized in that a hole injection layer is provided between the anode and the hole ~~transportation~~transport layer.

5. Please replace the paragraph bridging pages 45-46 at line 19 (the last line) of page 45 and at lines 1-7 of the specification with the following amended paragraph:

Then, on the NPB hole transport layer, an organic host material of the structural formula (1) and an organic guest material XT emitting red ~~phosphorescence~~phosphorescence among the compounds shown by the structural formula (6) were co-deposited from different vapor deposition sources to 475 Å thickness to form a light emitting layer. In this process, the concentration of the organic guest material XT in the light emitting layer was 7 wt%.

6. Please replace the paragraph on page 49 at lines 4-16 of the specification with the following amended paragraph:

~~For~~For the devices of Example 2 and the comparative example, Table 3 shows the light emitting characteristics during continuous driving at a constant current of 2.5 mA/cm², Fig. 5 shows voltage-luminance characteristics, and Fig. 6 shows current-luminance characteristics, respectively. The device of Example 2 using the material of the structural formula (1) of the invention for the host material in the light emitting layer had more satisfactory voltage-

luminance characteristics and current characteristics compared with the device of the comparative example. That is, the device of high efficiency and low driving voltage could be obtained by using the material shown by the structural formula (1) as the host material of the light emitting layer.